



Product data sheet

1. General description

WMS30N050V is a high performance logic level N-channel MOSFET in PDFN5X6 package, which utilizes advanced Trench MOSFET technology to provide low R_{DS(on)} and gate charge. It is designed and qualified in a wide range of industrial and consumer applications.



2. Features and benefits

- Advance High Cell Density Trench Technology
- Low $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$ to Minimize Conduction Losses • •
 - Low Capacitance to Minimize Switching Losses
- Optimized Gate Charge to Minimize Driver Losses
- 100% UIS Tested
- **RoHS** Compliant and Halogen Free •

3. Applications

- **DC-DC** Converters ٠
- **BLDC Motor Control**
- Load Switch
- Lithium-ion Battery Protection •

4. Quick reference data

Table 1. Qu	lick reference data						
Symbol	Parameter	Conditions	Notes	S Values			Unit
Absolute	maximum rating						
V _{DS}	drain-source voltage			30			V
V_{GS}	gate-source voltage				±20		V
I _D	continuous drain current	V _{GS} = 10 V; T _{mb} = 25 °C	[1]		71		А
P _{tot}	power dissipation	T _{mb} = 25 °C		42			W
Tj	junction temperature			-55 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						-
$R_{\text{DS(on)}}$	drain-source on-state	V _{GS} = 10 V, I _D = 20 A		-	4.1	5.0	mΩ
	resistance	V _{GS} = 4.5 V, I _D = 20 A		-	5.8	8.0	mΩ
Dynamic of	characteristics						
Q _{G(tot)}	total gate charge	$I_{\rm D}$ = 20 A; $V_{\rm DS}$ = 15 V; $V_{\rm GS}$ = 10 V		-	44	-	nC

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1-3	S	source	8 7 6 5	P
4	G	gate		
5-8	D	drain		G UF A

6. Ordering information

Table 3. Ordering information							
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date	
WMS30N050V	PDFN5X6	WMS30N050VJ	Reel	4000	PDFN5X6N	21-Jul-2022	

7. Marking

Table 4. Marking codes					
Type number	Marking codes				
WMS30N050V	WMS				
	30N050				

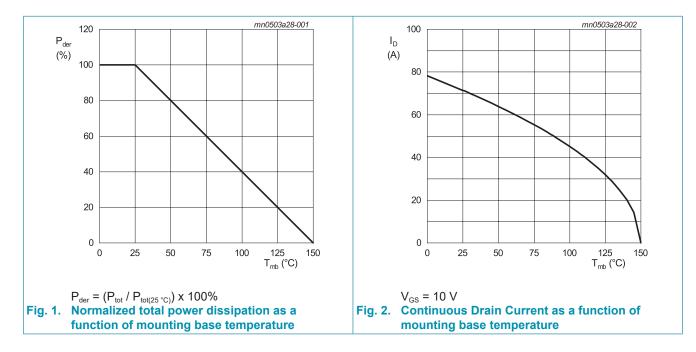
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			30	V
V _{GS}	gate-source voltage			±20	V
I _D	continuous drain current	V _{GS} = 10 V; T _{mb} = 25 °C	[1]	71	А
		V _{GS} = 10 V; T _{mb} = 120 °C		35	А
I _{DM}	pulsed drain current	t _p = 10 μs; T _{mb} = 25 °C		284	А
P _{tot}	power dissipation	T _{mb} = 25 °C		42	W
E _{as}	single pulse drain-to- source avalanche	I_{AS} = 28 A; L = 0.1 mH; R _{GS} = 25 Ω; V _{GS} = 10 V; T _j = 25 °C		39	mJ
T _{stg}	storage temperature			-55 to 150	°C
Tj	junction temperature			-55 to 150	°C

[1] Calculated continuous current based on maximum allowable junction temperature. Package current limitation is 50A.

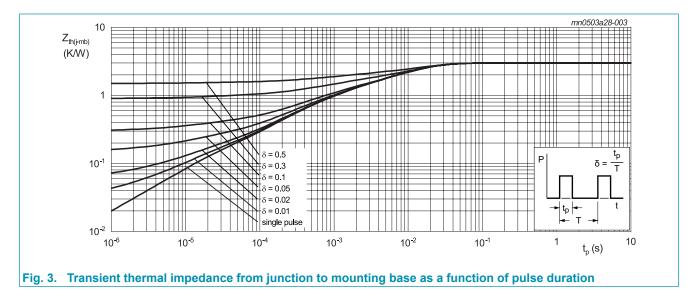


9. Thermal & Mechanical characteristics

Table 6. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base			-	2.3	3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[2]	-	-	55	K/W

[2] Surface mount on FR4 board of 1 inch², 1 oz copper.

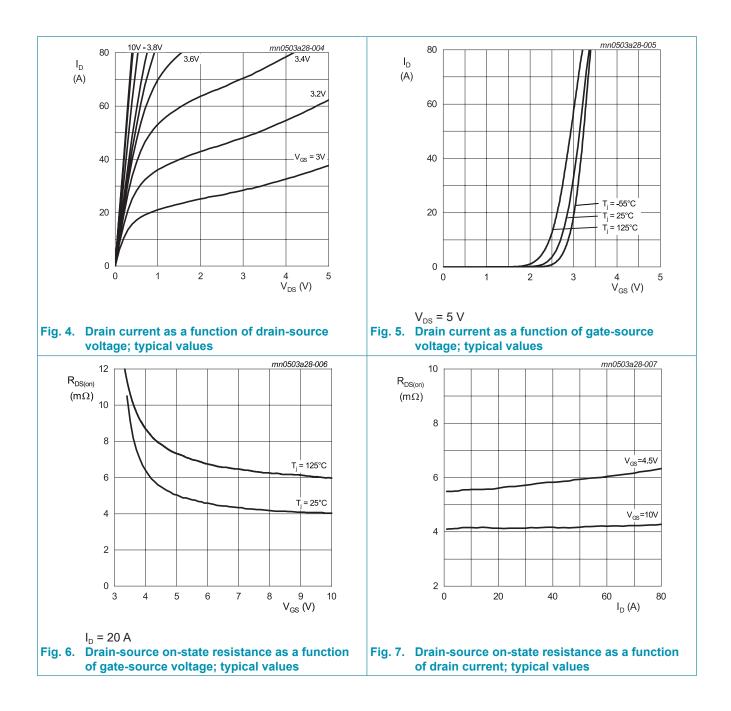


10. Characteristics

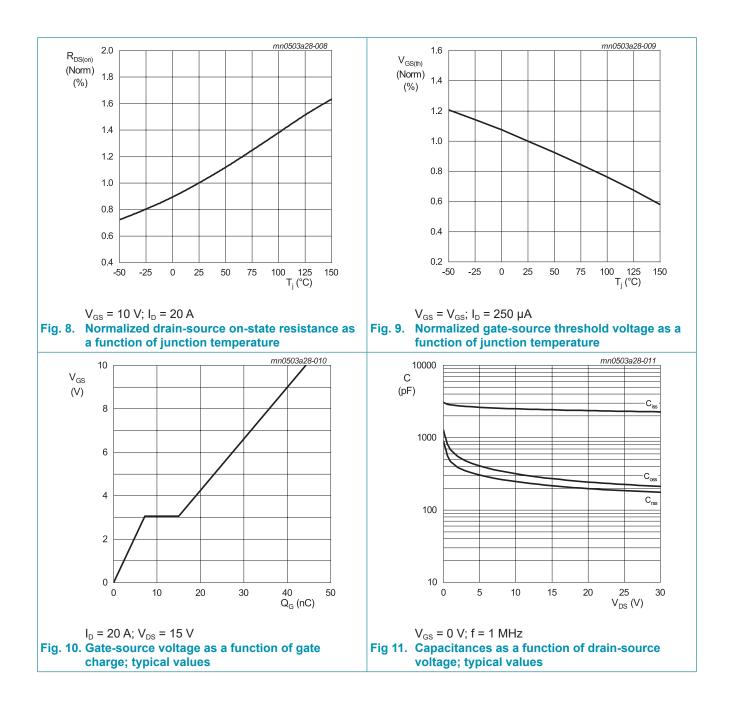
Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V		30	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS}		1.0	1.6	2.4	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V		-	-	1	μA
		V_{DS} = 30 V; V_{GS} = 0 V; T_j = 125 °C		-	-	10	μA
I _{GSS}	gate leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	±100	nA
$R_{\text{DS(on)}}$	drain-source on-state	V _{GS} = 10 V; I _D = 20 A		-	4.1	5.0	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 20 A		-	5.8	8.0	mΩ
R _G	gate resistance	f = 1 MHz		-	2.5	-	Ω
Dynamic	characteristics	·					
Q _{G(tot)}	total gate charge	$I_{\rm D}$ = 20 A; $V_{\rm DS}$ = 15 V; $V_{\rm GS}$ = 10 V		-	44	-	nC
Q _{GS}	gate-source charge			-	7.2	-	nC
Q_{GD}	gate-drain charge			-	7.8	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz		-	2433	-	pF
C _{oss}	output capacitance			-	272	-	pF
C _{rss}	reverse transfer capacitance			-	217	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 15 V; V_{GS} = 10 V; R_{G} = 6 \Omega;$		-	7.0	-	ns
t _r	rise time	I _D = 20 A		-	22	-	ns
$t_{d(off)}$	turn-off delay time			-	32	-	ns
t _f	fall time			-	25	-	ns
Source-d	rain diode	·	-				
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 1 A		-	0.71	1	V
		V _{GS} = 0 V; I _S = 1 A; T _j = 125 °C		-	0.54	-	V
ls	body-diode continuous current	T _{mb} = 25 °C		-	-	47	A
t _{rr}	reverse recovery time	V_{GS} = 0 V; I _S = 20 A; di/dt = 100 A/µs		-	16	-	ns
Q _{rr}	reverse recovered charge			-	8.0	-	nC
I _{rrm}	reverse recovery current			-	1.0	-	А

N-Channel Silicon MOSFET

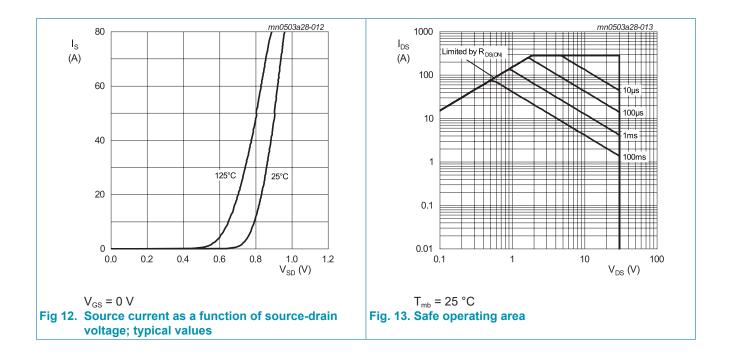


N-Channel Silicon MOSFET

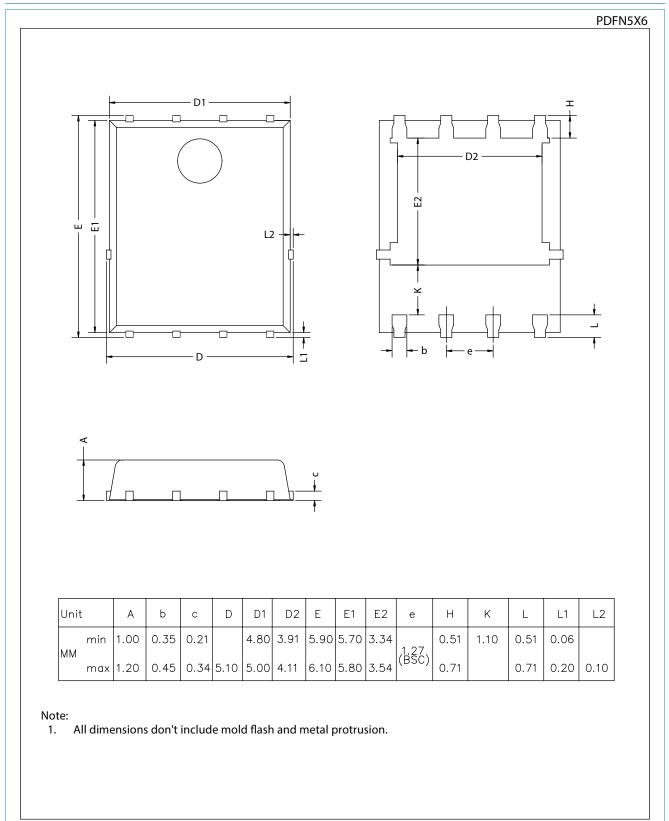


N-Channel Silicon MOSFET

WMS30N050V



11. Package outline



WMS30N050V

N-Channel Silicon MOSFET

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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